Power Transistor (-60V, -3A)

2SB1370

Features

- 1) Low saturation voltage, typically $V_{CE(sat)} = -0.3V$ at $I_{C} / I_{B} = -2A / -0.2A$
- 2) Excellent DC current gain characteristics.
- 3) $Pc = 2W(Ta=25^{\circ}C) / 30W(Tc=25^{\circ}C)$
- 4) Wide SOA (safe operating area).

Packaging specifications and hre

| Туре | 2SB1370 |
|------------------------------|----------|
| Package | TO-220FN |
| h _{FE} | EF |
| Code | - |
| Basic ordering unit (pleces) | 500 |

●Absolute maximum ratings (Ta=25℃)

| Parameter | Symbol | Limits | Unit | |
|-----------------------------|------------------|----------|------------|--|
| Collector-base voltage | V _{CBO} | -60 | V | |
| Collector-emitter voltage | V _{CEO} | -60 | V | |
| Emitter-base voltage | VEBO | -5 | V | |
| Collector current | I _c | -3 A(DC) | | |
| | I _{CP} | -6 | A(Pulse) * | |
| Collector power dissipation | | 2 | W | |
| | Po | 30 | W(Tc=25°C) | |
| Junction temperature | Тј | 150 | °C | |
| Storage temperature | Tstg | -55~+150 | J, | |

* Single pulse, Pw=100ms

●Electrical characteristics (Ta=25°C)

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions | |
|--------------------------------------|----------------------|------|------|------|------|--|---|
| Collector-base breakdown voltage | BV _{CBO} | -60 | — | - | V | $I_{\rm C} = -50 \mu {\rm A}$ | |
| Collector-emitter breakdown voltage | BV _{CEO} | -60 | — | - | V | I _c =-1mA | |
| Emitter-base breakdown voltage | BVEBO | -5 | — | - | V | I _E =-50 μ A | |
| Collector cutoff current | I _{CBO} | - | — | -10 | μA | V _{CB} =-60V | |
| Emitter cutoff current | IEBO | - | — | -10 | μA | V _{EB} =-4V | |
| Collector-emitter saturation voltage | V _{CE(sat)} | - | - | -1.5 | | I _C /I _B =-2A/-0.2A | * |
| Base-emitter saturation voltage | V _{BE(sat)} | - | - | -1.5 | | I _C /I _B =-2A/-0.2A | * |
| DC current transfer ratio | h _{FE} | 100 | — | 320 | — | V _{CE} /I _C =-5V/-0.5A | |
| Transition frequency | f⊤ | - | 15 | - | | V _{CE} =-5V, I _E =0.5A, f=5MHz | * |
| Output capacitance | Cob | - | 80 | - | pF | V _{CB} =-10V, I _E =0A, f=1MHz | |

* Measured using pulse current.

Power Transistor (-60V, -3A)

2SB1655/2SB1565

Features

- 1) Low saturation voltage, typically VCE(sat) =-0.3V at Ic / IB=-2A / -0.2A.
- 2) Excellent DC current gain characteristics.
- 3) Wide SOA (safe operating area).

●Packaging specifications and hre

| Туре | 2SB1655 | 2SB1565 |
|------------------------------|----------|----------|
| Package | TO-220FN | TO-220FN |
| h _{FE} | E | EF |
| Code | - | - |
| Basic ordering unit (pieces) | 500 | 500 |

●Absolute maximum ratings (Ta=25℃)

| Parameter | Symbol | Limits | Unit | |
|-----------------------------|------------------|------------------------|-------------|--|
| Collector-base voltage | - | -80 | V | |
| | V _{CBO} | | • | |
| Collector-emitter voltage | V _{CEO} | -60 | V | |
| Emitter-base voltage | VEBO | -7 | V | |
| Collector current | l _c | I _C —3 A (E | | |
| Collector current | I _{CP} | -6 | A (Pulse) * | |
| Collector power dissipation | Б | 2 | W | |
| | Pc | 25 | W(Tc=25°C) | |
| Junction temperature | Tj | 150 | °C | |
| Storage temperature | Tstg | -55~+150 | ç | |
| ★ Single pulse Pw=100ms | | | | |

* Single pulse, Pw=100ms

●Electrical characteristics (Ta=25℃)

| Paramet | er | Symbol | Min. | Тур. | Max. | Unit | Conditions | |
|--------------------------|------------------------|----------------------|---------------------|------|------|------|--|-----|
| Collector-base break | down voltage | BV _{CBO} | -80 | — | - | V | $I_{\rm C} = -50 \mu {\rm A}$ | |
| Collector-emitter brea | akdown voltage | BV _{CEO} | -60 | — | - | V | I _c =-1mA | |
| Emitter-base breakdo | wn voltage | BVEBO | -7 | - | - | V | $I_E = -50 \mu A$ | |
| Collector cutoff current | nt | I _{CBO} | - | — | -10 | μA | V _{CB} =-60V | |
| Emitter cutoff current | Emitter cutoff current | | - | — | -10 | μA | V _{EB} =-7V | |
| Collector-emitter | 2SB1655 | V _{CE(sat)} | - | - | -1 | V | 1.4 - 0.44 0.04 | * |
| saturation voltage | 2SB1565 | | — | - | -1.5 | V | I ₀ /I _B =-2A/-0.2A | 240 |
| Base-emitter saturation | on voltage | V _{BE(sat)} | - | - | -1.5 | V | I ₀ /I _B =-2A/-0.2A | |
| DC current | 2SB1655 | | 100 | - | 200 | - | X 4 - 5X4 0.5A | |
| transfer ratio | 2SB1565 | IFE | h _{FE} 100 | — | 320 | - | V _{CE} /I _C =-5V/-0.5A | |
| Transition frequency | ransition frequency | | - | 15 | - | MHz | V _{CE} =-5V, I _E =0.5A, f=5MHz | * |
| Output capacitance | | Cob | - | 50 | - | pF | V _{CB} =-10V, I _E =0A, f=1MHz | |

* Measured using pulse current.

(94L-456-B349)

(94L-411-B303)

ROHM

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